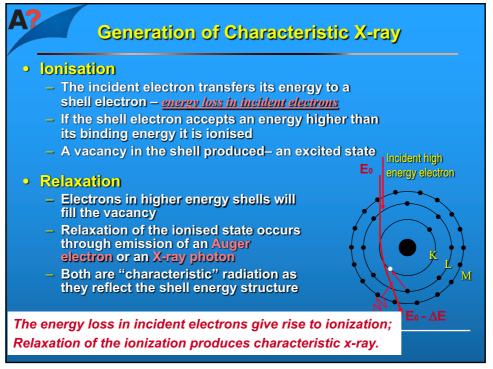
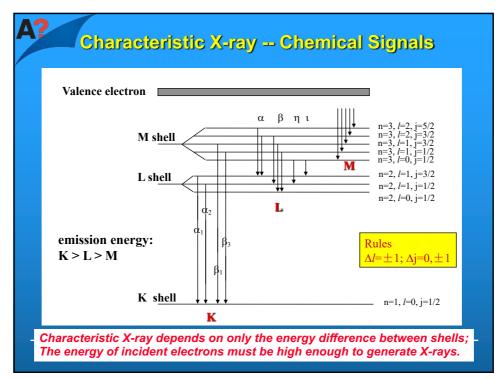
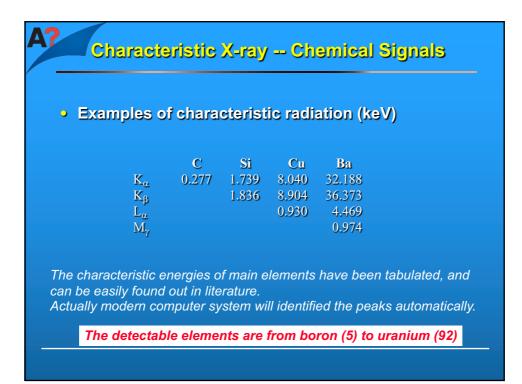
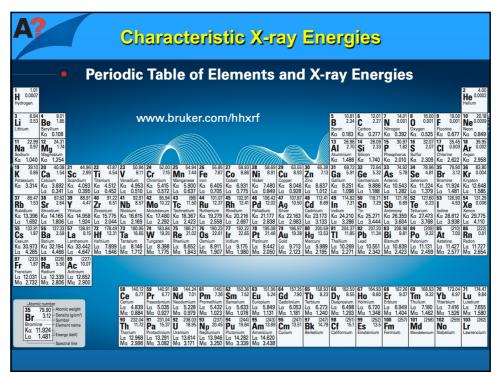


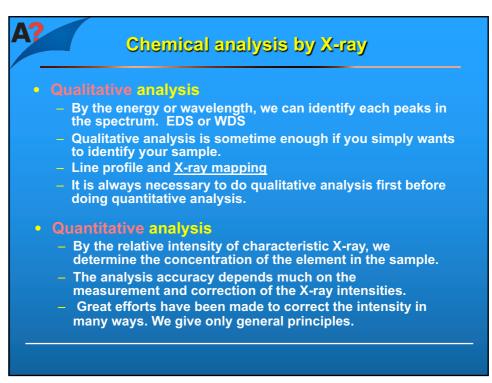
Device --- an optional tool attached to TEM Detector: generates a • charge pulse Computer proportional to X-ray energy, and then converted to a voltage. Electronic device: amplifying and processing weak signal Charge Energy X-ray pulse **Pulse** Detector processor data analysis and display 38

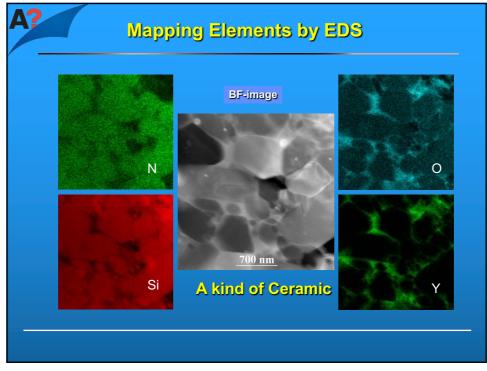


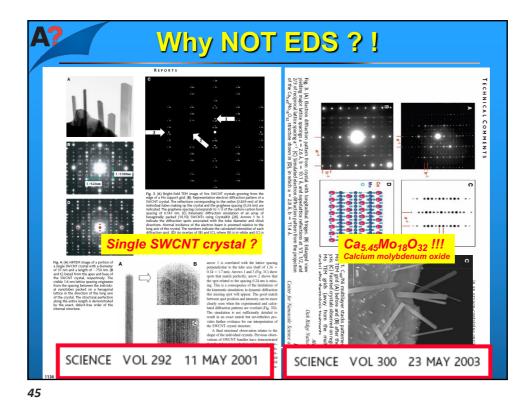


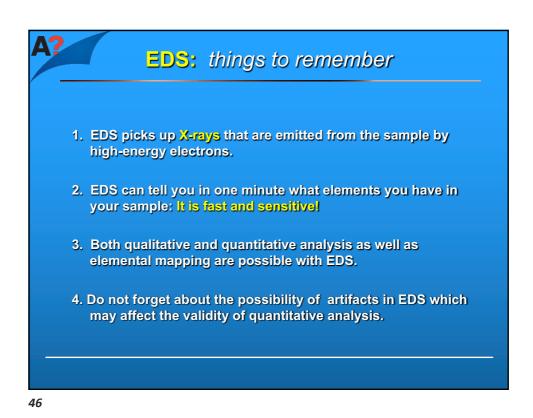


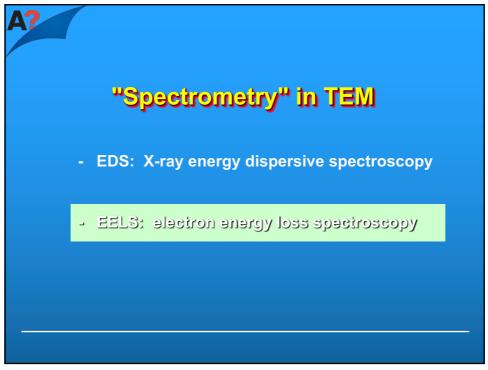


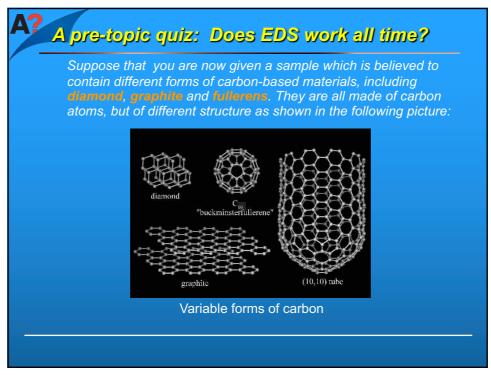


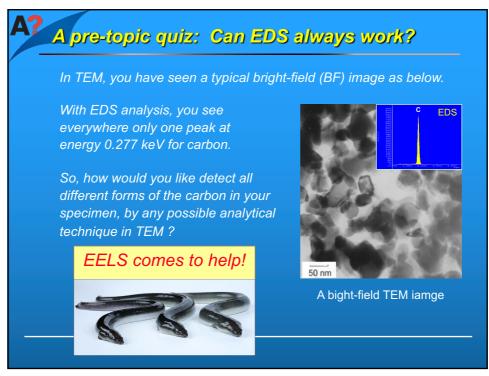


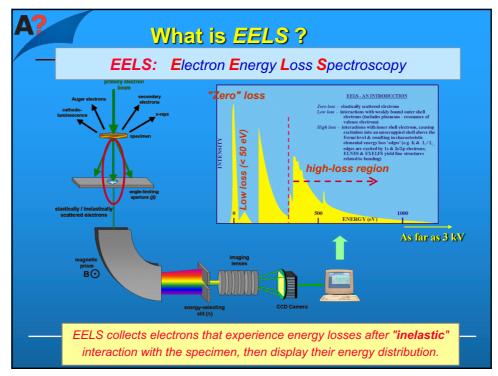


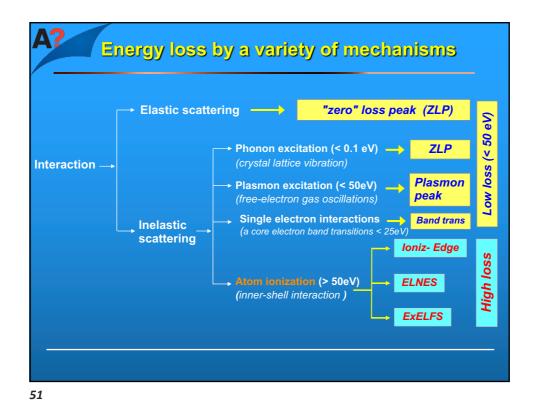


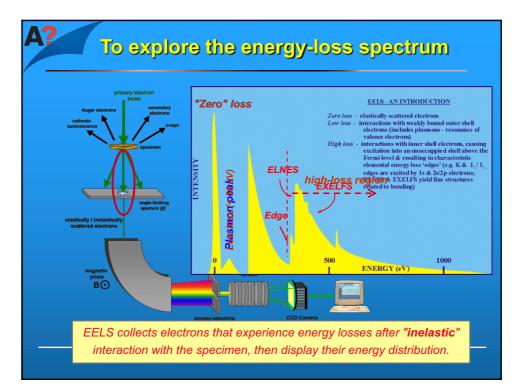


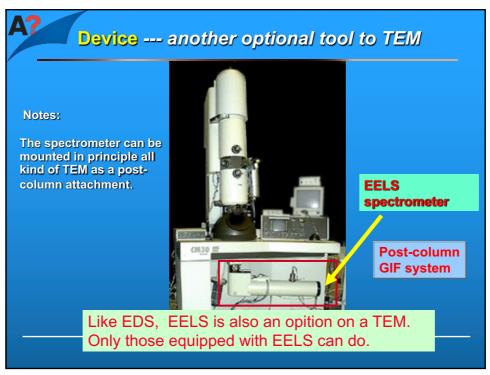


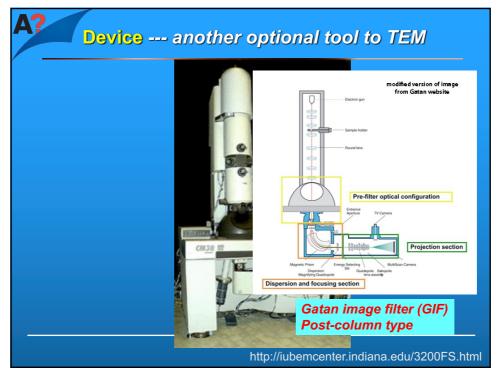


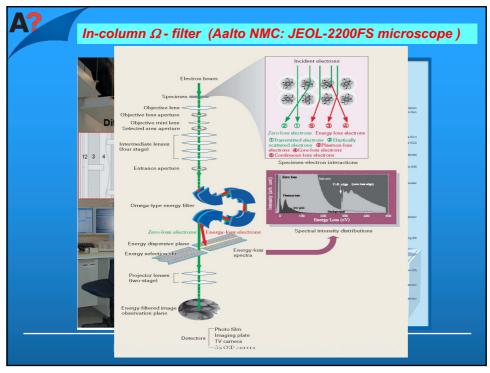


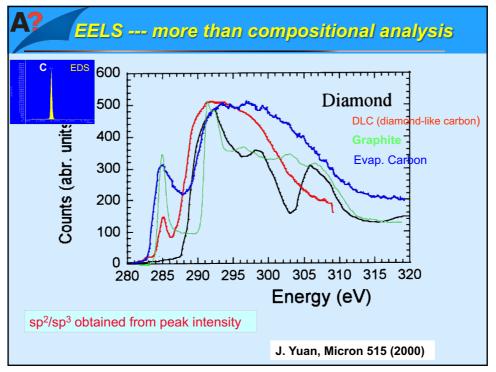


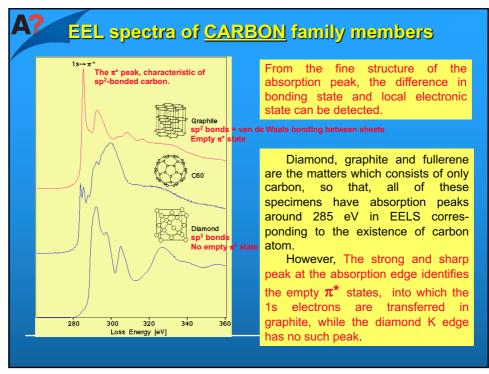


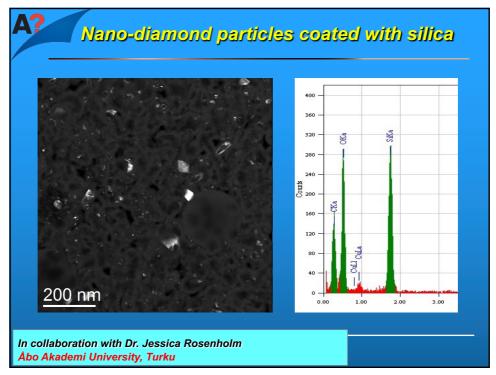


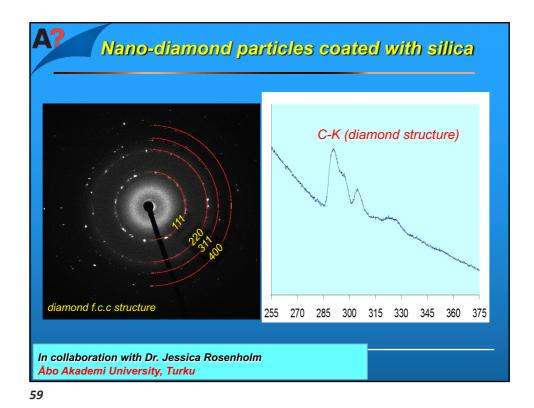


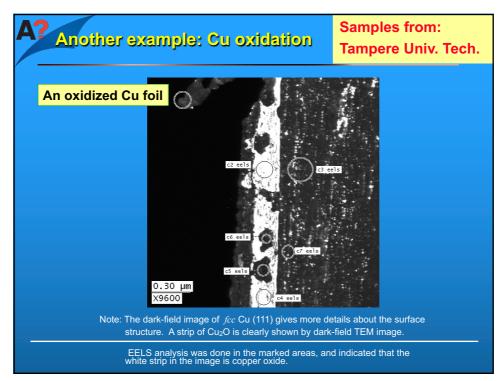


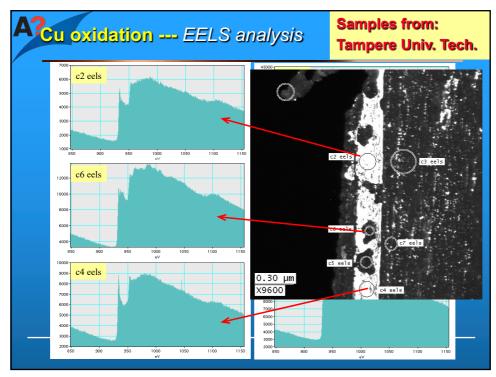


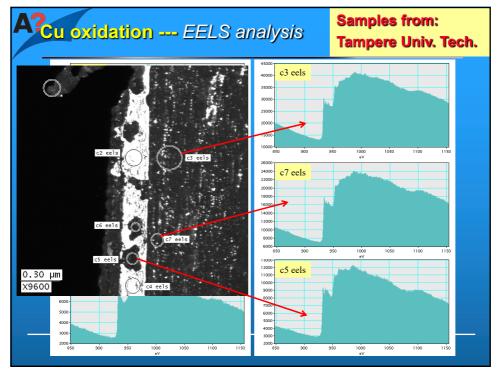


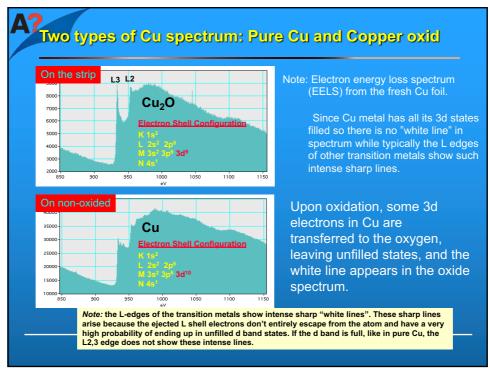


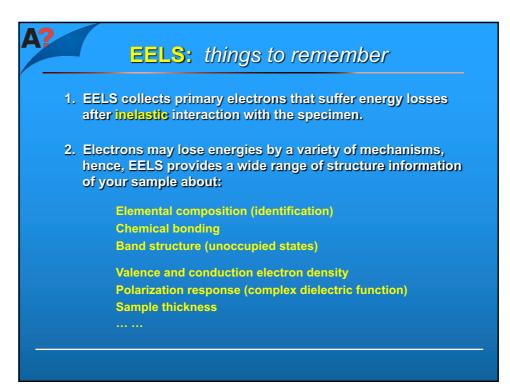












EELS vs. EDS --- too many differences

<u>EDS</u>

- X-rays provide elemental information only
- Inefficient signal generation, collection &detection inefficient x-ray mapping
- Slow technique (hours)
- X-ray spectra can contain information from column and other parts of sample
- High detection efficiency for high Z elements
- Energy resolution > 100eV causes frequent overlaps
- Only simple processing required

EELS

- Elemental, Chemical, & Dielectric information
- Very efficient in every respect => higher sensitivity to most elements very efficient mapping technique
- Fast technique (seconds to minutes)
- EELS spectra have no such artifacts
- High detection efficiency for low Z elements
- Energy resolution 0.3-2eV gives far fewer overlaps
- More complex processing required => Needs more hardware & software automation

65

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